



## Supplementary Information Improving the Dimensional Stability and Mechanical Properties of AISI 316L + B Sinters by Si<sub>3</sub>N<sub>4</sub> Addition

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Figure S1. Scheil–Gulliver solidification plot of sample 0-0.



Figure S2. Scheil–Gulliver solidification plot of sample 1-0.



Figure S3. Scheil–Gulliver solidification plot of sample 1-2.



Figure S4. Scheil–Gulliver solidification plot of sample 1-4.



Figure S5. Scheil–Gulliver solidification plot of sample 1-6.



Figure S6. Scheil–Gulliver solidification plot of sample 1-8.



Figure S7. Scheil–Gulliver solidification plot of sample 2-0.



Figure S8. Scheil–Gulliver solidification plot of sample 2-2.



Figure S9. Scheil–Gulliver solidification plot of sample 2-4.



Figure S10. Scheil–Gulliver solidification plot of sample 2-6.



Figure S11. Scheil–Gulliver solidification plot of sample 2-8.



Figure S12. Scheil–Gulliver solidification plot of sample 3-0.



Figure S13. Scheil–Gulliver solidification plot of sample 3-2.



Figure S14. Scheil–Gulliver solidification plot of sample 3-4.



Figure S15. Scheil–Gulliver solidification plot of sample 3-6.



Figure S16. Scheil–Gulliver solidification plot of sample 3-8.



Figure S17. Scheil–Gulliver solidification plot of sample 4-2.



Figure S18. Scheil–Gulliver solidification plot of sample 4-4.



Figure S19. Scheil–Gulliver solidification plot of sample 4-6.



Figure S20. The composition of Cr<sub>2</sub>B in sample 4-0.



Figure S21. The composition of Cr<sub>2</sub>B in sample 4-8.



Figure S22. The composition of M<sub>2</sub>B in sample 4-0.



Figure S23. The composition of M<sub>2</sub>B in sample 4-8.

**Table S1.** The calculations of secondary phases amount depending on the chemical composition of the samples.

	Description of samples														
0-0 1-0 1-2 1-4 1-6 1-8 2-0 2-2 2-4 2-6 2-8 3-0 3-2 3-4 3-6 3-8 4-0 4-2 4-4 4-	1-6 1-8 2-0 2-2 2-4 2-6 2-8 3-0 3-2 3-4 3-6 3-8 4-0 4-2	3-6 3-8 4-0 4	3-2 3-4	3-0	2-8	2-6	2-4	2-2	2-0	1-8	1-6	1-4	1-2	1-0	0-0

 $\frac{Phase}{M_2B\,0.000\,1.166\,1.168\,1.152\,1.101\,0.986\,2.126\,2.068\,2.058\,1.994\,1.928\,2.953\,2.965\,2.852\,2.790\,2.727\,3.783\,3.720\,3.614\,3.540\,3.452}\,amoun$ 

 $t\ /\ Cr_2B\ 0.000\ 0.117\ 0.075\ 0.062\ 0.026\ 0.000\ 0.704\ 0.589\ 0.543\ 0.474\ 0.434\ 1.322\ 1.181\ 1.086\ 1.045\ 1.017\ 2.024\ 1.879\ 1.737\ 1.631\ 1.556\ mole$ 

8N 0.0000.0000.0250.0740.1040.0770.0000.0750.1260.2120.3070.0000.1260.1850.2800.4110.0000.1600.2550.3790.490

Table S2. The influence of boron and silicon nitride on the relative density of cylindrical sample	les.
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			В	oron addition / wt	%	
		0.0	0.1	0.2	0.3	0.4
SS	0.0	78.95±0.19	81.17±0.22	82.63±0.22	90.14±0.25	93.01±0.26
ma / -	0.2	-	80.90±0.22	84.56±0.23	91.13±0.25	91.93±0.26
tio tio	0.4	-	80.36±0.21	84.75±0.23	90.90±0.25	92.57±0.26
ra <sup>3</sup> N4	0.6	-	80.56±0.21	82.60±0.23	90.61±0.25	88.97±0.24
Si	0.8	-	79.96±0.21	81.47±0.22	88.10±0.24	85.83±0.23

Table S3. Corrosion current of selected samples as a function of porosity.

Descriptions (second se	Icorr	Icorr st.dev.	Ecorr	Ecorrst.dev.	
Description of samples		μΑ	mV		
0-0	18.86	1.271	-305.2	1.144	
2-0	6.15	0.475	-315.8	0.330	
4-0	0.63	0.066	-272.4	8.674	
4-4	4.52	0.051	-338.7	7.270	
4-8	8.39	4.624	-320.7	5.564	

				Boron addition / v	wt %	
		0.0	0.1	0.2	0.3	0.4
SS	0.0	20±10	10±10	130±10	360±10	650±10
3N4/B mat ratio / -	0.2	-	50±10	120±10	350±10	490±10
	0.4	-	20±10	100±10	370±10	380±10
	0.6	-	20±10	80±0.01	320±10	260±10
Si	0.8	-	60±10	80±10	200±10	200±10

**Table S4.** Maximum dimensional distortions of  $\emptyset$ 20 × 5 mm cylindrical samples as a function of boron and silicon nitride additions.

Table S5. Density change of prismatic samples in the boron and silicon nitride addition functions.

		Boron addition / wt %								
		0.0	0.1	0.2	0.3	0.4				
ar	0.0	79.62±0.19	$77.71 \pm 0.18$	79.72±0.19	82.52±0.18	84.15±0.20				
	0.2	-	79.14±0.18	79.04±0.19	82.16±0.18	84.25±0.19				
/B 1 tio	0.4	-	77.76±0.19	79.86±0.18	81.12±0.19	82.12±0.19				
ra ra	0.6	-	79.65±0.19	79.97±0.18	82.05±0.19	81.02±0.19				
Si	0.8	-	77.48±0.18	80.35±0.19	80.91±0.19	80.35±0.18				

Table S6. Hardness as a function of boron addition for different silicon nitride additions.

		Boron addition / wt %			
Si <sub>3</sub> N <sub>4</sub> addition / wt %	Si <sub>3</sub> N <sub>4</sub> /B wt ratio / -	0.1	0.2	0.3	0.4
0	0	$62.9 \pm 2.4$	$58.9 \pm 3.0$	$71.1 \pm 0.9$	$132.3 \pm 2.1$
0.08	0.2	$71.4 \pm 3.0$	$60.5 \pm 1.4$	$74.5 \pm 2.0$	$146.3\pm6.0$
0.16	0.4	$69.6\pm4.4$	$74.0\pm1.3$	$88.0\pm2.4$	$154.7 \pm 5.2$
0.24	0.6	$66.9 \pm 5.1$	$69.9 \pm 2.0$	$108.7\pm12.4$	$148.7\pm0.9$
0.32	0.8	$64.0 \pm 0.7$	$77.9 \pm 2.9$	$123.0\pm5.4$	$154.3\pm6.9$

 Table S7. Influence of Si<sub>3</sub>N<sub>4</sub> and boron additions on transverse rupture strength (TRS).

 Boron addition / wt %

	-			Doron addition /	WL /o	
		0.0	0.1	0.2	0.3	0.4
ss	0.0	457±9	544±11	587±13	728±12	1002±23
3N4/B mai ratio / -	0.2	-	529±11	656±9	711±11	963±35
	0.4	-	548±7	670±17	720±18	975±26
	0.6	-	524±15	634±11	791±6	841±13
Si	0.8	-	563±15	658±14	847±15	775±5